CY74FCT2543T 8-BIT LATCHED TRANSCEIVER WITH 3-STATE OUTPUTS

SCCS042C - SEPTEMBER 1994 - REVISED NOVEMBER 2001

24 VCC

22 B₀

21 B1

20 B₂

19 B₃

18 B₄

17 B₅

16 B₆

15 B₇

13

14 LEAB

OEAB

23 CEBA

Q OR SO PACKAGE (TOP VIEW)

LEBA

OEBA [

2

А₀ [] з

A₁ 4

A₂ 5

A₄ [] 7

A₅ 8

A₆ 🛛 9

А7Ц

CEAB 11

GND [

10

12

A₃ 6

- Function and Pinout Compatible With FCT and F Logic
- 25-Ω Output Series Resistors to Reduce Transmission-Line Reflection Noise
- Reduced V_{OH} (Typically = 3.3 V) Versions of Equivalent FCT Functions
- Edge-Rate Control Circuitry for Significantly Improved Noise Characteristics
- I_{off} Supports Partial-Power-Down Mode Operation
- Matched Rise and Fall Times
- Fully Compatible With TTL Input and Output Logic Levels
- 12-mA Output Sink Current
 15-mA Output Source Current
- Separation Controls for Data Flow in Each Direction
- Back-to-Back Latches for Storage
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)
- 3-State Outputs

description

The CY74FCT2543T octal latched transceiver contains two sets of eight D-type latches. Separate latch enable (LEAB, LEBA) and output enable (OEAB, OEBA) inputs permit each latch set to have independent control of inputting and outputting in either direction of data flow. For example, for data flow from A to B, the A-to-B enable (CEAB) input must be low to enter data from A or to take data from B, as indicated in the function table. With CEAB low, a low signal on the A-to-B latch enable (LEAB) input makes the A-to-B latches transparent; a subsequent low-to-high transition of LEAB puts the A latches in the storage mode and their outputs no longer change with the A inputs. With CEAB and OEAB both low, the 3-state B output buffers are active and reflect data present at the output of the A latches. Control of data from B to A is similar, but uses CEAB, LEAB, and OEAB inputs. On-chip termination resistors at the outputs reduce system noise caused by reflections. The CY74FCT2543T can replace the CY74FCT543T to reduce noise in an existing design.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.



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PIN DESCRIPTION

NAME	DESCRIPTION						
OEAB	A-to-B output-enable input (active low)						
OEBA	B-to-A output-enable input (active low)						
CEAB	A-to-B enable input (active low)						
CEBA	B-to-A enable input (active low)						
LEAB	A-to-B latch-enable input (active low)						
LEBA	B-to-A latch-enable input (active low)						
А	A-to-B data inputs or B-to-A 3-state outputs						
В	B-to-A data inputs or A-to-B 3-state outputs						

ORDERING INFORMATION

TA	PACI	(AGE [†]	SPEED (ns)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QSOP – Q	Tape and reel	5.3	CY74FCT2543CTQCT	FCT2543C
	SOIC – SO	Tube	5.3	CY74FCT2543CTSOC	FCT2543C
		Tape and reel	5.3	CY74FCT2543CTSOCT	FC12543C
–40°C to 85°C	QSOP – Q	Tape and reel	6.5	CY74FCT2543ATQCT	FCT2543A
	SOIC – SO	Tube	6.5	CY74FCT2543ATSOC	FCT2543A
	5010 - 50	Tape and reel	6.5	CY74FCT2543ATSOCT	FC12543A
	QSOP – Q	Tape and reel	8.5	CY74FCT2543TQCT	FCT2543

[†]Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE

	INPUTS			OUTPUT		
CEAB	LEAB	OEAB	А-ТО-В‡	В		
Н	Х	Х	Storing	Z		
х	Н	Х	Storing	Х		
х	Х	Н	х	Z		
L	L	L	Transparent	Current A inputs		
L	Н	L	Storing	Previous A inputs		

[‡]Before LEAB low-to-high transition

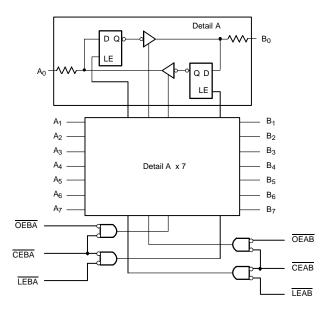
H = High logic level, L = Low logic level, X = Don't care,

Z = High-impedance state

A-to- \overline{B} data flow shown; B-to-A is the same, except using \overline{CEBA} , \overline{LEBA} , and \overline{OEBA} .



functional block diagram



absolute maximum rating over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range to ground potential	–0.5 V to 7 V
DC input voltage range	–0.5 V to 7 V
DC output voltage range	–0.5 V to 7 V
DC output current (maximum sink current/pin)	120 mA
Package thermal impedance, θ_{JA} (see Note 1): Q package	61°C/W
SO package	46°C/W
Ambient temperature range with power applied, T _A	–65°C to 135°C
Storage temperature range, T _{stg}	−65°C to 150°C
•	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 2)

		MIN	NOM	MAX	UNIT
Vcc	Supply voltage	4.75	5	5.25	V
VIH	High-level input voltage	2			V
VIL	Low-level input voltage			0.8	V
ЮН	High-level output current			-15	mA
I _{OL}	Low-level output current			12	mA
TA	Operating free-air temperature	-40		85	°C

NOTE 2: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	UNIT
VIK	V _{CC} = 4.75 V,	= 4.75 V, I _{IN} = -18 mA					
VOH	V _{CC} = 4.75 V,	√, l _{OH} = −15 mA					V
VOL	V _{CC} = 4.75 V,	I _{OL} = 12 mA			0.3	0.55	V
R _{out}	V _{CC} = 4.75 V,	I _{OL} = 12 mA		20	25	40	Ω
V _{hys}	All inputs				0.2		V
IН	V _{CC} = 5.25 V	$V_{IN} = V_{CC}$			5 ±1	μA	
١ _{IL}	V _{CC} = 5.25 V,	$V_{IN} = 0.5 V$	$V_{\rm IN} = 2.7 V$				μA
IOZH	$V_{\rm CC} = 5.25 \text{V},$	V _{OUT} = 2.7 V			15	μA	
IOZL	V _{CC} = 5.25 V,	V _{OUT} = 0.5 V			-15	μA	
los‡	V _{CC} = 5.25 V,	V _{OUT} = 0 V	-60	-120	-225	mA	
l _{off}	V _{CC} = 0 V,	V _{OUT} = 4.5 V			±1	μA	
ICC	V _{CC} = 5.25 V,	$V_{IN} \leq 0.2V$,		0.1	0.2	mA	
∆ICC	V _{CC} = 5.25 V, V _{IN} = 3.4 V§, f			0.5	2	mA	
ICCD	$\frac{V_{CC}}{CEAB} = 5.25 \text{ V}, \text{ One input switc} \\ \overline{CEAB} \text{ and } \overline{OEAB} = LOW, \overline{CEE} \\ V_{IN} \le 0.2 \text{ V or } V_{IN} \ge V_{CC} - 0 \\ \end{array}$	BA = HIGH,	utputs open,		0.06	1.2	mA/ MHz
	V _{CC} = 5.25 V, f ₀ = 10 MHz,	One bit switching at f ₁ = 5 MHz	$\begin{array}{l} V_{IN} \leq 0.2 \ V \ or \\ V_{IN} \geq V_{CC} - 0.2 \ V \end{array}$		0.7	1.4	
IC#	$\frac{\text{Outputs open,}}{\text{CEAB}} = \text{LOW,}$	at 50% duty cycle	$V_{IN} = 3.4 \text{ V or GND}$		1.2	3.4	
۱ <i>۲</i>	$\frac{CEAB}{CEBA} = HIGH,$ f ₀ = LEAB = 10 MHz	Eight bits switching at f ₁ = 5 MHz	$\begin{array}{l} V_{IN} \leq 0.2 \ V \ or \\ V_{IN} \geq V_{CC} - 0.2 \ V \end{array}$			5.6	- mA
			50% duty cycle $V_{IN} = 3.4 \text{ V or GND}$		5.1	14.6	
Ci					5	10	pF
Co					9	12	pF

[†] Typical values are at $V_{CC} = 5 V$, $T_A = 25^{\circ}C$.

[‡] Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample-and-hold techniques are preferable to minimize internal chip heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output can raise the chip temperature well above normal and cause invalid readings in other parametric tests. In any sequence of parameter tests, IOS tests should be performed last.

§ Per TTL-driven input (V_{IN} = 3.4 V); all other inputs at V_{CC} or GND

- This parameter is derived for use in total power-supply calculations.
- [#]IC $= I_{CC} + \Delta I_{CC} \times D_H \times N_T + I_{CCD} (f_0/2 + f_1 \times N_1)$
- Where:
- = Total supply current IC
- I_{CC} = Power-supply current with CMOS input levels
- ΔI_{CC} = Power-supply current for a TTL high input (VIN = 3.4 V)
- D_H = Duty cycle for TTL inputs high
- NT = Number of TTL inputs at DH
- I_{CCD} = Dynamic current caused by an input transition pair (HLH or LHL)
- = Clock frequency for registered devices, otherwise zero fo
- = Input signal frequency f1
- = Number of inputs changing at f1 N1

All currents are in milliamperes and all frequencies are in megahertz.

I Values for these conditions are examples of the ICC formula.



timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

		METER	CY74FC	T2543T	CY74FCT	2543AT	CY74FCT2	UNIT	
	FARA	MIN	MAX	MIN	MAX	MIN	MAX	UNIT	
tw	Pulse duration, LEBA or	5		5		5		ns	
t _{su}	Setup time, high or low	A or B before $\overline{\text{LEBA}}\downarrow$ or $\overline{\text{LEAB}}\downarrow$	2		2		2		ns
^t h	Hold time, high or low	A or B after $\overline{\text{LEBA}}\downarrow$ or $\overline{\text{LEAB}}\downarrow$	2		2		2		ns

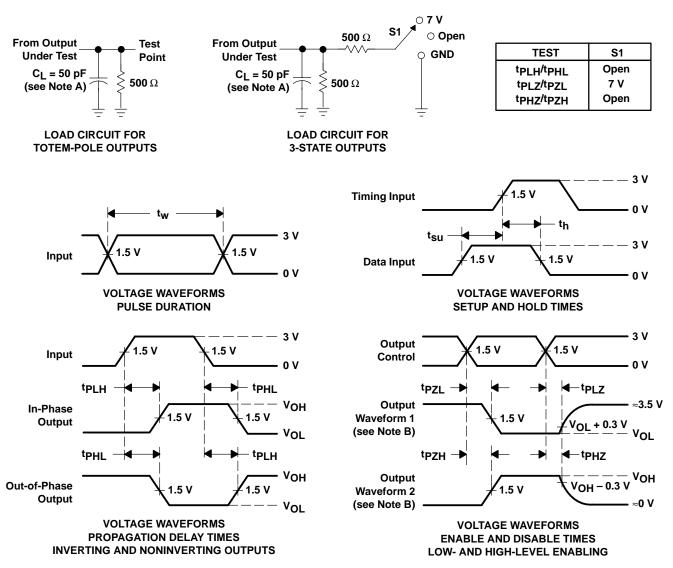
switching characteristics over operating free-air temperature range (see Figure 1)

PARAMETER	FROM	то	CY74FC	T2543T	CY74FCT	2543AT	CY74FCT2543CT		UNIT
PARAMETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
^t PLH	A or B	B or A	2.5	8.5	2.5	6.5	2.5	5.5	ns
^t PHL	AUB	BOIX	2.5	0.0	2.5	0.5	2.0	5.5	115
^t PLH	LEBA or LEAB	A or B	2.5	12.5	2.5	8	2.5	7	ns
^t PHL		AOLP	2.5	12.5	2.5	0	2.0	'	115
^t PZH	OEBA or OEAB	DEBA or OEAB A or B		12	2	9	2	8	ns
^t PZL		AUB	2	12	2	9	2	8	110
^t PZH		A	2	12	2	9	2	8	20
^t PZL	CEBA or CEAB	A or B	2	12	2	9	2	8	ns
^t PHZ	0504	A at D	2	9	2	7.5	2	6.5	
^t PLZ	OEBA or OEAB	A or B	2	9	2	7.5	2	6.5	ns
^t PHZ	CEBA or CEAB	A or B	2	9	2	7.5	2	6.5	
^t PLZ		A Of B	2	9	2	7.5	2	6.5	ns



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PARAMETER MEASUREMENT INFORMATION

- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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21-May-2007

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
74FCT2543ATSOCTE4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74FCT2543ATSOCTG4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74FCT2543CTSOCTE4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74FCT2543CTSOCTG4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2543ATQCT	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT2543ATQCTE4	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT2543ATQCTG4	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT2543ATSOC	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2543ATSOCE4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2543ATSOCG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2543ATSOCT	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2543CTQCT	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT2543CTQCTE4	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT2543CTQCTG4	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT2543CTSOC	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2543CTSOCE4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2543CTSOCG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2543CTSOCT	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT2543TQCT	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT2543TQCTE4	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT2543TQCTG4	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR

(1) The marketing status values are defined as follows: ACTIVE: Product device recommended for new designs. LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.



(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. TBD: The Pb-Free/Green conversion plan has not been defined.

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Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CY74FCT2543ATQCT	SSOP/ QSOP	DBQ	24	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT2543ATSOCT	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
CY74FCT2543CTQCT	SSOP/ QSOP	DBQ	24	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT2543CTSOCT	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
CY74FCT2543TQCT	SSOP/ QSOP	DBQ	24	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1



PACKAGE MATERIALS INFORMATION

11-Mar-2008



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CY74FCT2543ATQCT	SSOP/QSOP	DBQ	24	2500	346.0	346.0	33.0
CY74FCT2543ATSOCT	SOIC	DW	24	2000	346.0	346.0	41.0
CY74FCT2543CTQCT	SSOP/QSOP	DBQ	24	2500	346.0	346.0	33.0
CY74FCT2543CTSOCT	SOIC	DW	24	2000	346.0	346.0	41.0
CY74FCT2543TQCT	SSOP/QSOP	DBQ	24	2500	346.0	346.0	33.0

DBQ (R-PDSO-G24)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.

D. Falls within JEDEC MO-137 variation AE.



DW (R-PDSO-G24)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AD.



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